GTL2005

Quad GTL/GTL+ to LVTTL/TTL bidirectional non-latched translator

Rev. 07 — 3 February 2009 Product data sheet

1. General description

The GTL2005 is a quad translating transceiver designed for 3.3 V system interface with a GTL/GTL+ bus.

The direction pin (DIR) allows the part to function as either a GTL-to-TTL sampling receiver or as a TTL-to-GTL interface.

The GTL2005 LVTTL interface is tolerant up to 5.5 V allowing direct access to TTL or 5 V CMOS outputs.

The GTL2005 V_{ref} linearity degrades below 0.8 V (see Section 10.1). If the application allows, use the GTL2014, otherwise more closely review noise margins.

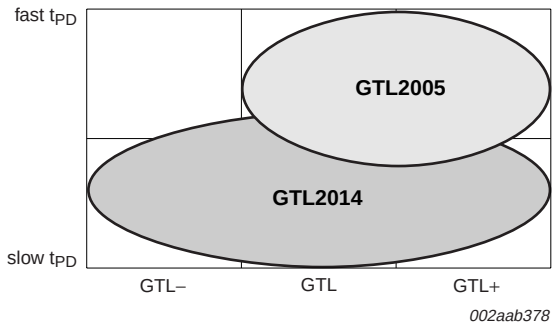


Fig 1. GTL2005/GTL2014 positioning

2. Features

- Operates as a quad GTL/GTL+ sampling receiver or as a LVTTL/TTL to GTL/GTL+ driver
- Quad bidirectional bus interface
- 3.0 V to 3.6 V operation with 5 V tolerant LVTTL I/O
- Live insertion/extraction permitted
- Latch-up protection exceeds 500 mA per JESD78
- ESD protection exceeds 2000 V HBM per JESD22-A114, 150 V MM per JESD22-A115, and 1000 V CDM per JESD22-CC101
- Package offered: TSSOP14

3. Quick reference data

Table 1. Quick reference data

V_{CC} = 3.3 V ± 0.3 V

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
C_i	input capacitance	control inputs; V_I = 3.0 V or 0 V	-	2.3	3.5	pF
C_{io}	input/output capacitance	A port; $V_O = V_{TT}$ or 0 V	-	3.4	5.0	pF
		B port; V_O = 3.0 V or 0 V	-	6.0	7.0	pF
GTL; V_{ref} = 0.8 V						
t_{PLH}	propagation delay, Bn to An	see Figure 7	-	2.1	2.3	ns
t_{PHL}			-	1.9	2.6	ns
t_{PLH}	propagation delay, An to Bn	see Figure 8	-	4.1	5.9	ns
t_{PHL}			-	4.4	5.9	ns

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

4. Ordering information

Table 2. Ordering information

T_{amb} = −40 °C to +85 °C

Type number	Topside mark	Package		
		Name	Description	Version
GTL2005PW	GTL2005	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1

5. Functional diagram

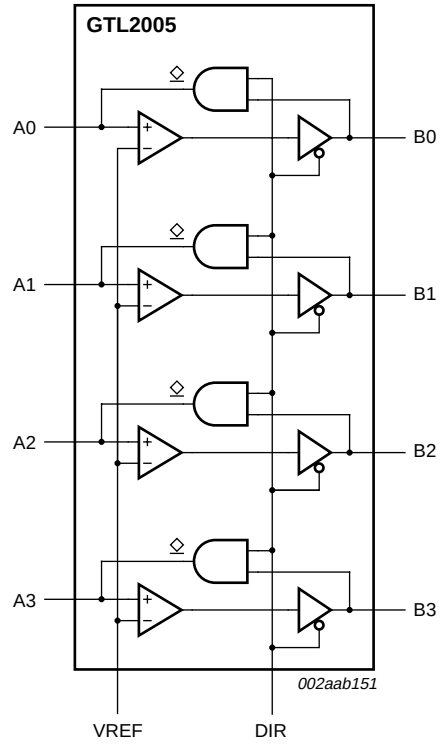


Fig 2. Logic diagram of GTL2005

6. Pinning information

6.1 Pinning

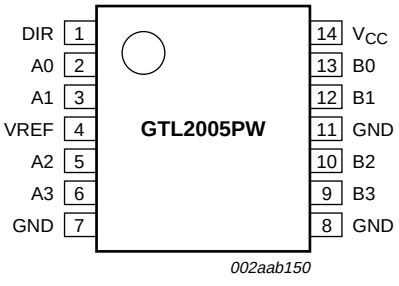


Fig 3. Pin configuration for TSSOP14

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
DIR	1	direction control input
A0	2	data inputs/outputs (A side, GTL)
A1	3	
A2	5	
A3	6	
B0	13	data inputs/outputs (B side, TTL)
B1	12	
B2	10	
B3	9	
VREF	4	GTL reference voltage
GND	7, 8, 11	ground (0 V)
V_{CC}	14	positive supply voltage

7. Functional description

Refer to Figure 2 “Logic diagram of GTL2005”.

7.1 Function table

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Input/output	
DIR	**B (TTL)**	**A (GTL)**
H	inputs	Bn = An
L	An = Bn	inputs

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).[1]
Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	DC supply voltage		–0.5	+4.6	V
I_{IK}	DC input diode current	$V_I < 0$ V	-	–50	mA
V_I	DC input voltage	A port	–0.5[2]	+7.0	V
		B port	–0.5[2]	+4.6	V
I_{OK}	DC output diode current	$V_O < 0$ V	-	–50	mA
V_O	DC output voltage	output in OFF or HIGH state; A port	–0.5[2]	+7.0	V
		output in OFF or HIGH state; B port	–0.5[2]	+4.6	V
I_{OL}	current into any output in the LOW state	B port	-	128	mA
		A port	-	80	mA
I_{OH}	current into any output in the HIGH state	B port	-	–64	mA
T_{stg}	storage temperature range	[3]	–60	+150	°C

[1] Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Section 9 “Recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[2] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[3] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

9. Recommended operating conditions

Table 6. Operating conditions [1]

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CC}	supply voltage			3.0	3.3	3.6	V
V_{TT}	termination voltage	GTL–		0.85	0.9	0.95	V
		GTL		1.14	1.2	1.26	V
		GTL+		1.35	1.5	1.65	V
V_{ref}	reference voltage	overall	[2]	0.5	$^2/_3V_{TT}$	1.8	V
		GTL–		0.5	0.6	0.63	V
		GTL		0.76	0.8	0.84	V
		GTL+		0.87	1.0	1.10	V
V_I	input voltage	A port		0	V_{TT}	3.6	V
		except A port		0	3.3	5.5	V
V_{IH}	HIGH-level input voltage	A port	[3]	-	-		V
		except A port		2	-	-	V
V_{IL}	LOW-level input voltage	A port		-	-	[3]	V
		except A port		-	-	0.8	V
I_{OH}	HIGH-level output current	B port		-	-	–12	mA
I_{OL}	LOW-level output current	A port		-	-	40	mA
		B port		-	-	12	mA
T_{amb}	ambient temperature	operating in free-air		–40	-	+85	°C

[1] Unused inputs must be held HIGH or LOW to prevent them from floating.

[2] V_{ref} is normally $^2/_3V_{TT}$, but based upon application and noise margin requirements can be set anywhere within this range and does not need to follow GTL-/GTL/GTL+ specification.

[3] Nominally ±50 mV around V_{ref}. See Figure 4, Figure 5, and Figure 6 for actual performance versus V_{ref}, V_{CC}, and temperature.

10. Static characteristics

Table 7. Static characteristics

Recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = −40 °C to +85 °C.

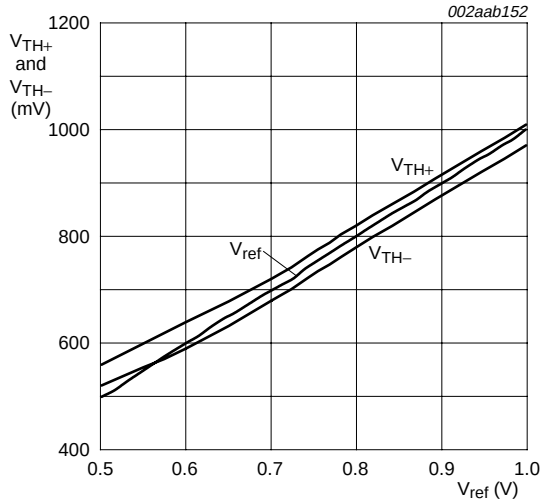
Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
V_{OH}	HIGH-level output voltage	B port; V_{CC} = 3.0 V to 3.6 V; I_{OH} = −100 µA	[2]	V_{CC} − 0.2	-	-	V
		B port; V_{CC} = 3.0 V; I_{OH} = −12 mA	[2]	2.0	-	-	V
V_{OL}	LOW-level output voltage	A port; V_{CC} = 3.0 V; I_{OL} = 40 mA	[2]	-	-	0.4	V
		B port; V_{CC} = 3.0 V; I_{OL} = 4 mA	[2]	-	-	0.4	V
		B port; V_{CC} = 3.0 V; I_{OL} = 8 mA	[2]	-	-	0.55	V
		B port; V_{CC} = 3.0 V; I_{OL} = 12 mA	[2]	-	-	0.8	V
I_I	input current	control inputs; V_{CC} = 3.6 V; V_I = V_{CC} or GND		-	-	±1	µA
		A port; V_{CC} = 3.6 V; V_I = V_{TT} or GND		-	-	±1	µA
		B port; V_{CC} = 0 V or 3.6 V; V_I = 5.5 V		-	-	10	µA
		B port; V_{CC} = 3.6 V; V_I = V_{CC}		-	-	±1	µA
		B port; V_{CC} = 3.6 V; V_I = 0 V		-	-	−5	µA
I_{OFF}	output OFF current	A port; V_{CC} = 0 V; V_I or V_O = 0 V to 4.5 V		-	-	±100	µA
I_{EX}	high contention over voltage leakage current	B port; V_{CC} = 3.0 V; V_O = 5.5 V		-	50	125	µA
I_{CC}	supply current	A or B port; V_{CC} = 3.6 V; V_I = V_{CC} or GND; I_O = 0 mA		-	-	3	mA
ΔI_{CC}[3]	additional supply current per input	B port or control inputs; V_{CC} = 3.6 V; V_I = V_{CC} − 0.6 V		-	-	500	µA
C_i	input capacitance	control inputs; V_I = 3.0 V or 0 V		-	2.3	3.5	pF
C_{io}	input/output capacitance	A port; V_O = V_{TT} or 0 V		-	3.4	5.0	pF
		B port; V_O = 3.0 V or 0 V		-	6.0	7.0	pF

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

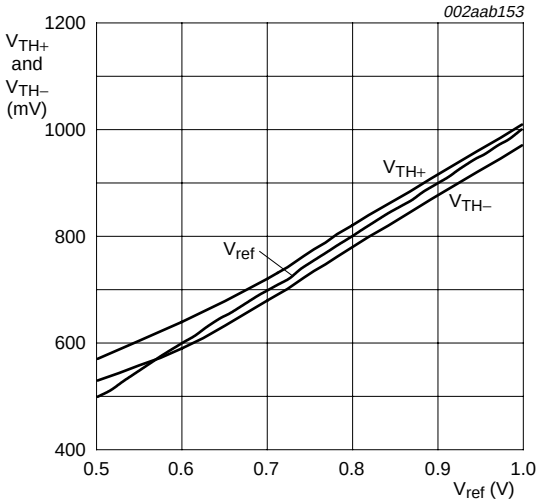
[2] The input and output voltage ratings my be exceeded if the input and output current ratings are observed.

[3] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

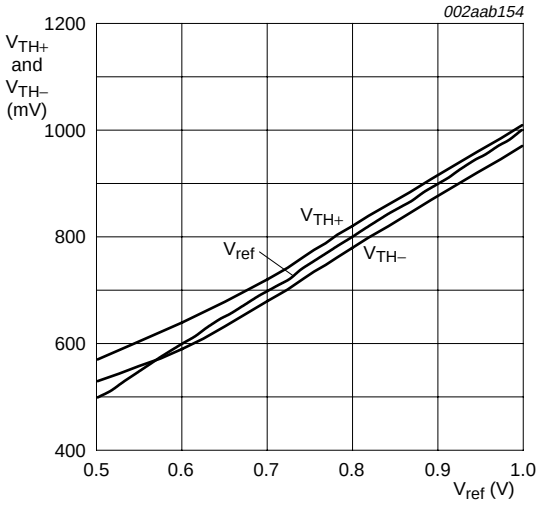
10.1 Performance curves



a. V_{CC} = 3.0 V

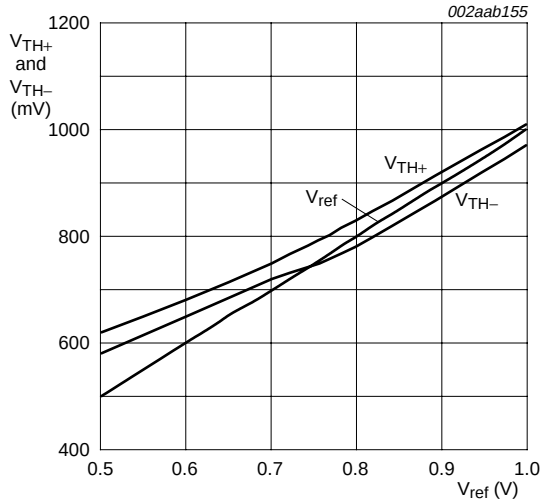


b. V_{CC} = 3.3 V

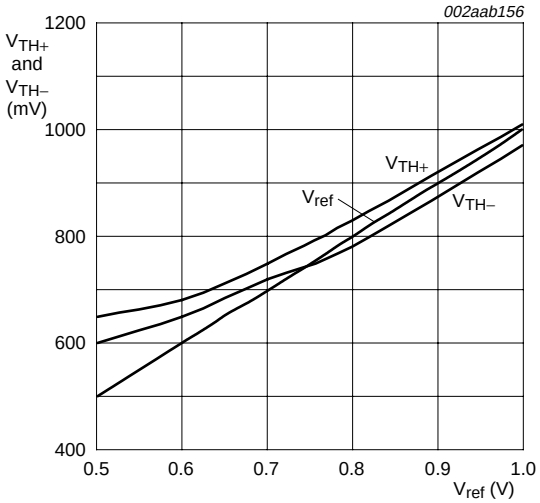


c. V_{CC} = 3.6 V

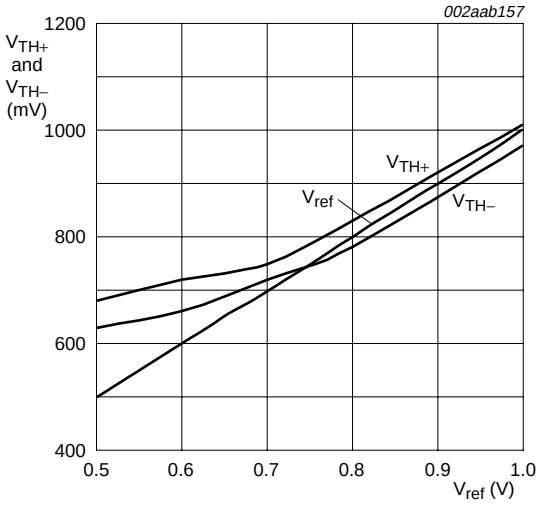
Fig 4. GTL V_{TH+} and V_{TH-} versus V_{ref}; T_{amb} = −40 °C



a. V_{CC} = 3.0 V

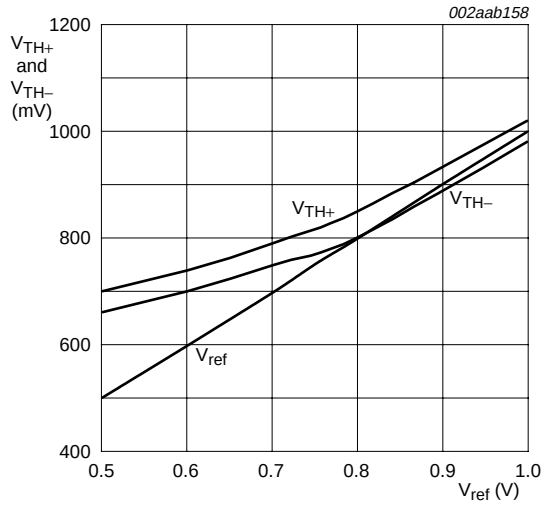


b. V_{CC} = 3.3 V

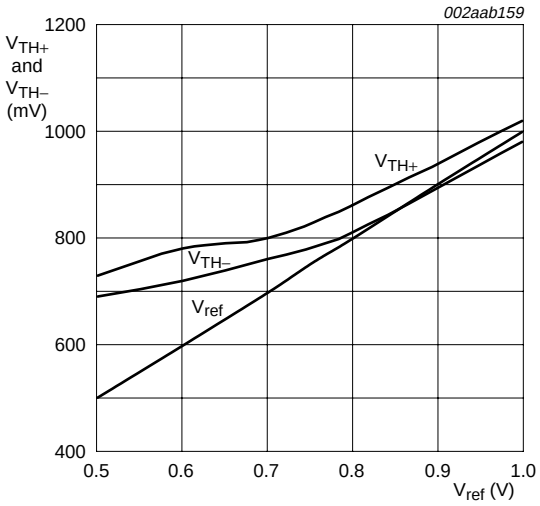


c. V_{CC} = 3.6 V

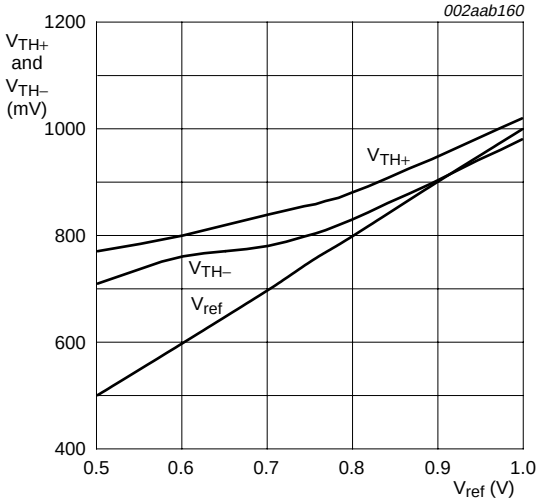
Fig 5. GTL V_{TH+} and V_{TH-} versus V_{ref}; T_{amb} = +25 °C



a. V_{CC} = 3.0 V



b. V_{CC} = 3.3 V



c. V_{CC} = 3.6 V

Fig 6. GTL V_{TH+} and V_{TH-} versus V_{ref}; T_{amb} = +85 °C

11. Dynamic characteristics

Table 8. Dynamic characteristics

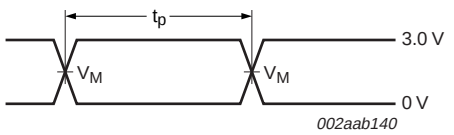
V_{CC} = 3.3 V ± 0.3 V

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
GTL−; V_{ref} = 0.6 V						
t_{PLH}	propagation delay, Bn to An	see Figure 7	-	2.1	2.3	ns
t_{PHL}			-	1.9	2.6	ns
t_{PLH}	propagation delay, An to Bn	see Figure 8	-	4.1	5.9	ns
t_{PHL}			-	4.4	5.9	ns
GTL; V_{ref} = 0.8 V						
t_{PLH}	propagation delay, Bn to An	see Figure 7	-	2.1	2.3	ns
t_{PHL}			-	1.9	2.6	ns
t_{PLH}	propagation delay, An to Bn	see Figure 8	-	4.1	5.9	ns
t_{PHL}			-	4.4	5.9	ns
GTL+; V_{ref} = 1.0 V						
t_{PLH}	propagation delay, Bn to An	see Figure 7	-	2.1	2.3	ns
t_{PHL}			-	1.9	2.6	ns
t_{PLH}	propagation delay, An to Bn	see Figure 8	-	4.2	5.7	ns
t_{PHL}			-	3.8	5.4	ns

[1] All typical values are at V_{CC} = 3.3 V and T_{amb} = 25 °C.

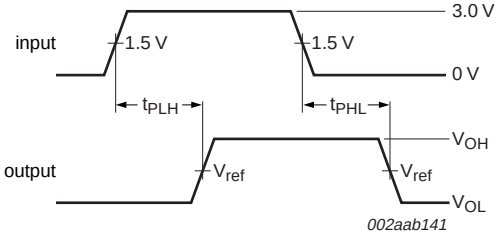
11.1 Waveforms

V_M = 1.5 V at $V_{CC} \geq$ 3.0 V; $V_M = V_{CC}/2$ at $V_{CC} \leq$ 2.7 V for B ports and control pins; $V_M = V_{ref}$ for A ports.



V_M = 1.5 V for B port and V_{ref} for A port

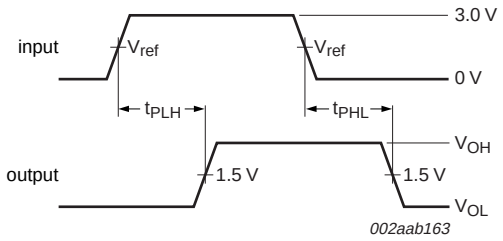
a. Pulse duration



B port to A port

b. Propagation delay times

Fig 7. Voltage waveforms



PRR ≤ 10 MHz; Z_o = 50 Ω; t_r ≤ 2.5 ns; t_f ≤ 2.5 ns

Fig 8. Propagation delay, An to Bn

12. Test information

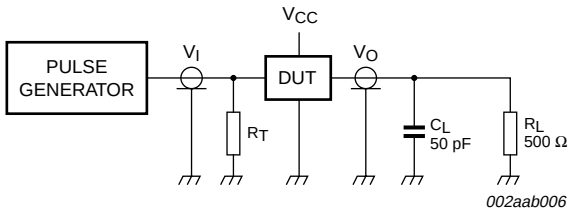


Fig 9. Load circuitry for switching times

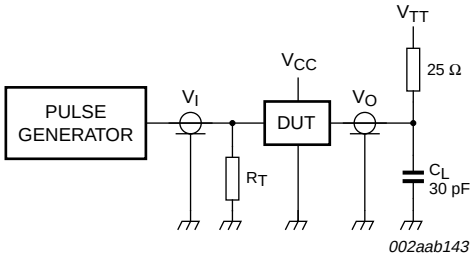


Fig 10. Load circuit for A (GTL) outputs

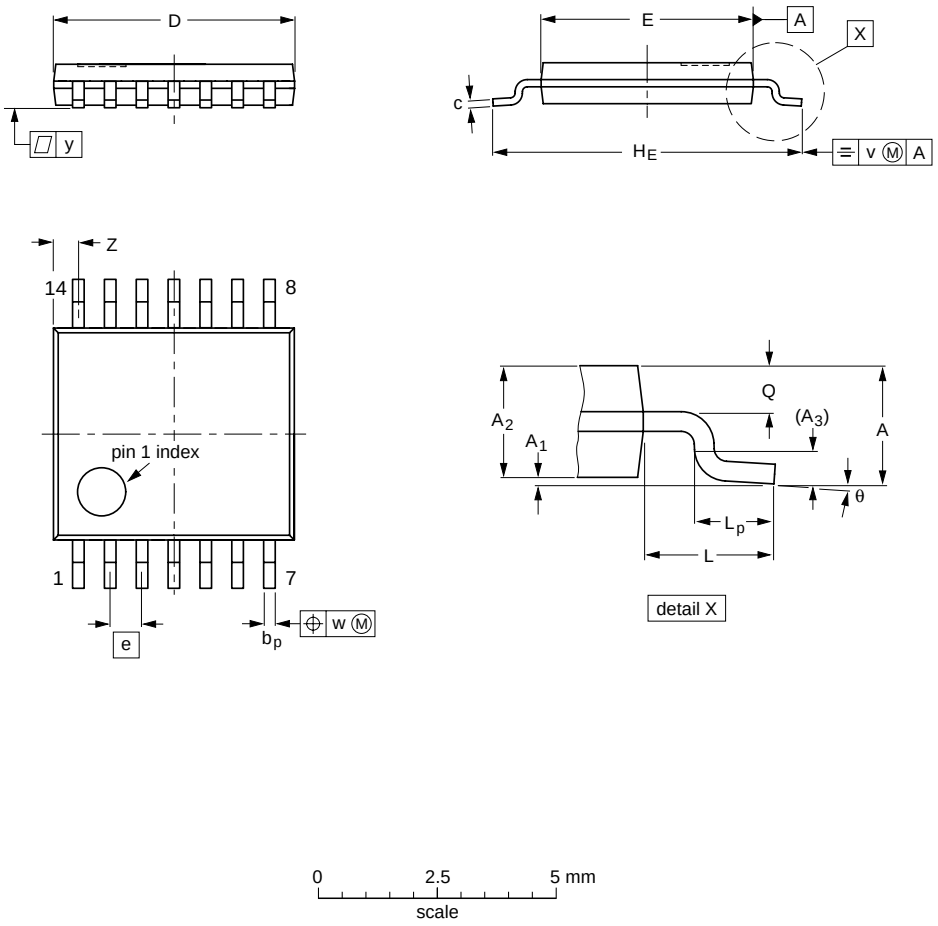
R_L — Load resistor

C_L — Load capacitance; includes jig and probe capacitance

R_T — Termination resistance; should be equal to Z_o of pulse generators.

13. Package outline

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm **SOT402-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D (1)	E (2)	e	H_E	L	L_p	Q	v	w	y	Z (1)	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8^o 0^o

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				~~99-12-27~~ 03-02-18

Fig 11. Package outline SOT402-1 (TSSOP14)

14. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

14.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

14.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

14.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

14.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see Figure 12) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 9 and 10

Table 9. SnPb eutectic process (from J-STD-020C)

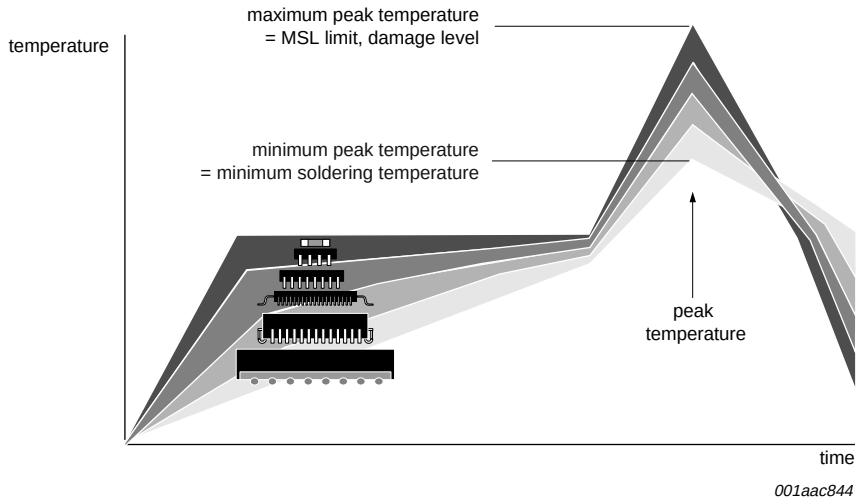
Package thickness (mm)	Package reflow temperature (°C)	
	Volume (mm^3)	
	< 350	≥ 350
< 2.5	235	220
≥ 2.5	220	220

Table 10. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm^3)		
	< 350	350 to 2000	> 2000
< 1.6	260	260	260
1.6 to 2.5	260	250	245
> 2.5	250	245	245

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 12.



MSL: Moisture Sensitivity Level

Fig 12. Temperature profiles for large and small components

For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

15. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged-Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
GTL	Gunning Transceiver Logic
HBM	Human Body Model
I/O	Input/Output
LVTTL	Low Voltage Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
GTL2005_7	20090203	Product data sheet	-	GTL2005_6
Modifications:	• Figure 2 “Logic diagram of GTL2005” modified: symbol for AND gate replaced and its direction reversed • updated soldering information			
GTL2005_6	20070906	Product data sheet	-	GTL2005_5
GTL2005_5 (9397 750 14285)	20050406	Product data sheet	-	GTL2005_4
GTL2005_4 (9397 750 13104)	20040510	Product data	-	GTL2005_3
GTL2005_3 (9397 750 07222)	20000619	Product data	853-2171 23901	GTL2005_2
GTL2005_2 (9397 750 06695)	19990917	Product data	853-2171 22353	GTL2005_1
GTL2005_1 (9397 750 06497)	19990917	Product data		-

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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18. Contact information

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19. Contents

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English

GTL2005

Quad GTL/GTL+ to LVTTL/TTL bidirectional non-latched translator

Products / Packages

Type number	Orderable part number	Ordering code (12NC)	Product status	Package	Packing	Marking	ECCN
GTL2005PW/DG	GTL2005PW/DG,118	9352 858 97118	Volume production	SOT402-1 (TSSOP14)	Reel Pack, SMD, 13"	Standard Marking	
GTL2005PW	GTL2005PW,112	9352 638 13112	Volume production	SOT402-1 (TSSOP14)	Tube	Standard Marking	
GTL2005PW	GTL2005PW,118	9352 638 13118	Volume production	SOT402-1 (TSSOP14)	Reel Pack, SMD, 13"	Standard Marking	

The variants in the table below are discontinued. See the table Discontinuation information at the bottom of this page for more information.

Type number	Orderable part number	Ordering code (12NC)	Product status	Package	Packing	Marking	ECCN
GTL2005PW/G	GTL2005PW/G,118	9352 764 14118	Withdrawn **Replacement product**	SOT402-1 (TSSOP14)	Reel Pack, SMD, 13"	Standard Marking	

Discontinuation information

Type number	Ordering code (12NC)	Last-time buy date	Last-time delivery date	Replacement product	DN Notice	Status	Comments
GTL2005PW/G	935276414118	31-Mar-11	30-Jun-11	**GTL2005PW**	DN 66	■ Sole source product ■ Standard availability	Standard End of Life. Discontinued /G version only.